Research Article
Femtosecond Laser-Induced Formation of Wurtzite Phase ZnSe Nanoparticles in Air

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The nanometer sized materials have provided an opportunity to study the relation between material properties and size. Due to the uniquely dimension-dependent properties, the nanosized material has the potential for various applications such as nanoelectronics, nanosensors, nanooptronics, and chemical catalyst [1–3]. The nanostructures of zinc selenide (ZnSe), in particular, have attracted considerable attention. ZnSe is an important II–VI semiconductor due to its promising optoelectrical and electrical properties of direct wide band gap 2.68 eV at 300 K. The ZnSe nanoparticles can be obtained through chemical reduction [4], vapor synthesis [5], or laser ablation method [6]. Generally, crystalline ZnSe exhibits two structural phases, that is, zinc blende and wurtzite [7]. However, the studies on wurtzite phase ZnSe nanoparticles are few [8–10] owing to that the wurtzite structure is thermodynamically unstable in ambient environments and requires the critical growth conditions. Recently, the femtosecond (fs) laser ablation has been extensively used for material processing [11–15]. Because of the unique features, in fs time-scale pulse duration and high power density (~GW/cm²), the high quality nanosized materials can be obtained without thermal effects. For instance, nanospike [12], nanowire [14], and nanoparticle [13, 15] have been produced through this approach. In this study, we present a handy way to fabricate pure ZnSe nanoparticles in metastable wurtzite structure through femtosecond laser ablation technique. The structural phase transition from zinc blende to wurtzite takes place during the processing and the size of nanoparticles is controllable by adjusting the laser fluences. Additionally, the characteristics and formation mechanism of ZnSe nanoparticles was investigated.

The fs laser pulses used in this study were provided by a Ti: sapphire regenerative amplifier with 800 nm and 80 fs at a repetition rate of 5 kHz. The linearly polarized laser pulses were focused by a planoconvex fused silica cylindrical lens with the focal length of 100 mm at normal incidence. The spot size on the surface of samples is 2270 μm × 54 μm. The pulse energy was varied from 0 to 260 mJ/cm² by using...
metallic neutral density filters with OD0.1–OD2 (Thorlabs ND series). A double-side polished (100) ZnSe wafer (5 mm × 5 mm × 0.5 mm) was mounted on a motorized x-y-z translation stage with the scanning speed of 100 μm/s. After laser irradiation, a pale yellow powder, that is, ZnSe nanoparticles, was observed on the surface of a processed ZnSe crystal. Depending on the experimental purpose, the nanoparticles were preserved in two different ways, that is, dissolved in ethanol with ultrasonic waves or picked up with Scotch tape. After removing the ZnSe powder, there were many subwavelength ripples shown on the surface of a laser ablated ZnSe wafer. The direction of ripples was perpendicular to the polarization of laser beam and laser scanning path which is consistent with the scenario of the interference between incident beam and scattering laser light [16]. The morphology of ZnSe single crystals, before and after laser ablation, was examined using a scanning electron microscope (SEM). Moreover, the X-ray diffraction, the Raman scattering spectra, transmission electron microscopy (TEM), and the selected area electron diffraction were applied to identify the structure and characteristics of laser-induced ZnSe nanoparticles.

Figure 1(a) shows a typical TEM image of ZnSe nanoparticles with the smooth spherical shape. The diameters of ZnSe nanoparticles are in the range of tens nanometer. In the selected area electron diffraction (SAED) pattern, a six-fold symmetry was clearly observed in Figure 1(b). Through the analysis of distance and angles between the nearest diffraction points and the center biggest point, the crystal structure of ZnSe nanoparticles was identified as a hexagonal (wurtzite) and the orientation of each diffraction point was marked in Figure 1(b). Furthermore, the energy dispersive
X-ray spectra (EDX) showed that Zn and Se are the only elements detected in the laser fabricated nanoparticles and the molar ratio of zinc and selenium is close to 1:1 (see the inset of Figure 1(a)). During the femtosecond laser irradiation, the dense plasma is formed on the sample surface via multiphoton absorption [17]. The ablated plume was confined near the laser focused region by surrounding air which prevents other ingredients of air, such as nitrogen, oxygen, and carbon dioxide, to get involved in the formation process of ZnSe nanoparticles under ambient environment. The size distribution of ZnSe nanoparticles fabricated at various fluences was analyzed in Figure 1(c). By fitting with the log-normal function, the average diameter of ZnSe nanoparticles was determined to be approximately 16 nm in the case of 135 mJ/cm². With an increase in the laser fluence to 198 mJ/cm² and 220 mJ/cm², the average size of the ZnSe nanoparticles slightly increased to 20 nm and 22 nm, respectively. Although the variation of average size (~6 nm) is smaller than the statistic bar width of 10 nm in Figure 1(c) (determined by the variation of average size of ZnSe nanoparticles under same fluences, which is caused by the fluctuations of laser fluences, pulse durations, spectra, and so on.), the higher fluence indeed generate more ZnSe nanoparticles with larger size. This indicates that the size distribution of ZnSe nanoparticles can be controlled by adjusting laser fluence and increases as the laser fluence rises. Furthermore, the generation rate of ZnSe nanoparticles using fs laser pulses is approximately $3.63 \times 10^{10} \text{s}^{-1}$ (or $7.26 \times 10^6$ per pulse) with a fluence of 135 mJ/cm². For the higher fluence of 220 mJ/cm², the generation rate of ZnSe nanoparticles increased by one order of magnitude to $3.63 \times 10^{11} \text{s}^{-1}$ (or $7.26 \times 10^7$ per pulse).

In Figure 2(a), X-ray diffraction patterns revealed the structures of a ZnSe single-crystal wafer and the ZnSe nanoparticles fabricated under various laser fluences are zinc blende and wurtzite, respectively, according to the JCPDS card no. 80-0021 ($a = 5.618$ Å) and no. 80-0008 ($a = b = 3.974$ Å, $c = 6.506$ Å) for ZnSe. It can be clearly seen that the zinc blende phase of a ZnSe single-crystal wafer has been transferred to the wurtzite phase in the ZnSe nanoparticles. Because wurtzite ZnSe is a metastable phase under ambient conditions, it can only be observed under high pressure and high temperature conditions. However, wurtzite ZnSe nanoparticles can be easily and reliably
achieved using femtosecond laser ablation as demonstrated in this study. Additionally, the room-temperature Raman scattering spectra of samples was measured by micro-Raman system as shown in Figure 2(b). The typical Raman scattering peaks of ZnSe nanoparticles were clearly observed from 200 to 250 cm\(^{-1}\) which are rather different from that of ZnSe single crystal wafer. Moreover, there was no vibration mode due to impurities observed in the Raman spectra which is consistent with the above EDX results. A look at the Raman single crystal wafer. Moreover, there was no vibration mode and surface phonon mode, the theoretical expression of surface phonon mode (\(S\)) of nanoparticles. This phenomenon, appearance of surface phonon mode, can be decidedly observed in small-sized material \([9, 20]\) due to the small average size and more uniform size distribution. In order to figure out the relation between TO phonon mode and surface phonon mode, the theoretical expression was used as follows \([20]\):

\[
\frac{\omega_s^2}{\omega_T^2} = \frac{\varepsilon_0 + \varepsilon_m(1/L) - 1}{\varepsilon_\infty + \varepsilon_m(1/L) - 1},
\]

where \(\omega_s\) and \(\omega_T\) represent the surface phonon and TO phonon frequency, respectively; \(\varepsilon_0\) and \(\varepsilon_\infty\) are static and high-frequency dielectric constant, respectively; \(\varepsilon_m\) is the dielectric constant of surrounding medium and \(L\) indicates the depolarization factor which is related to the particle shape. In the case of ZnSe, \(\omega_T = 203\) cm\(^{-1}\), \(\varepsilon_0 = 8.6\), \(\varepsilon_\infty = 5.7\), and \(\varepsilon_m\) is equal to 1 for air surrounding condition \([18]\). Because the laser-fabricated ZnSe nanoparticles are in spherical shape, according to the TEM image shown in Figure 1 (a), the depolarization factor \((L)\) is 1/3. Using (1), the calculated surface phonon mode is located at 238 cm\(^{-1}\) which is consistent with the measured value of 232 cm\(^{-1}\). It is worth to note that the LO, TO, and surface phonon modes are strongly fluence dependent. As the laser fluence decreases, the LO and TO peaks gradually shrink; meanwhile, the surface phonon mode increases. In the case of 135 ml/cm\(^2\), the surface phonon mode almost dominates the Raman spectra, which is due to the smaller average size and more uniform size distribution as shown in Figure 1 (c). Additionally, the small-size nanoparticles also result in the red shift of surface phonon mode.

According to the early researches, ZnSe transforms from a zinc blende structure to the wurtzite phase when the temperature is above the transition temperature \((T_e)\) of 1698 K \([7]\). When ZnSe crystals are irradiated by the femtosecond laser pulses, the temperature of electrons and lattice in ZnSe crystals increases according to the two-temperature model \([21]\). Because of the much smaller heat capacity in electron subsystem, the increase of electron temperature is dramatically larger than that of the lattice. The electron temperature \(T_e\) can be described by \([22]\)

\[
T_e = \left( \frac{T_t^2 + \frac{2(1-R)F}{\lambda y} e^{-z/l}}{1+e^{l/z}} \right)^{1/4},
\]

where \(R\) is the reflectivity at 800 nm and \(F\) is the laser fluences and \(\gamma\) is the linear coefficient of heat capacity due to the electronic subsystem. The mean value is taken for the depth \(z\) going from the crystal surface down to the skin depth \(l \sim 1.87\) μm (it was estimated from the nonlinear absorption coefficient \(\beta [23]\)). In this study, taking \(T_t = 295\) K, \(R = 0\) (which is assumed to be totally absorbed by ZnSe), \(F = 220\) ml/cm\(^2\), and \(\gamma = 29.4\) ml mol\(^{-1}\) K\(^{-1}\) \([24]\), we obtain \(T_e \sim 1200\) K. However, for the structure transition in materials, the key factor is the lattice temperature rather than the electron temperature. Thus, we further consider the increase in the transient temperature \(\Delta T_e\) in materials can be estimated according to the relationship of \(\Delta T_e = W/(C \times V)\), where \(W\) is the pulse energy, \(C\) is the heat capacity, and \(V\) is the illuminated volume. For ZnSe at 300 K, \(C \approx 1.89 \times 10^6\) J/m \(^3\) K \([7]\), \(V = 2.29 \times 10^{-13}\) m\(^3\) (absorption depth 1.87 μm estimated from the nonlinear absorption coefficient \(\beta [23]\)), and \(W\) is in the order of 0.243 ml (which is assumed to be totally absorbed by ZnSe). Thus, the \(\Delta T_e\) is approximately 560 K, which is far below the structural transition temperature of 1698 K. Therefore, a structural transition could not be induced by the increase in temperature. To identify the mechanism underlying the phase transition of ZnSe from zinc blende to wurtzite, we further analyzed the influence of “ablation pressure” \([25]\), which has been studied from various perspectives over the past few decades \([26, 27]\). When solids are irradiated by laser pulses, high-density plasma is formed on the surface of the samples \([17]\). The compressed plasma in laser driven implosions has been characterized as the ablating or exploding pusher according to the surface ablation pressure and bulk pressure due to the preheating through electrons.

In 2003, Batani et al. \([25]\) derived the shock pressure with the laser and target parameters expressed as

\[
P(Mbar) = 11.6 \left( \frac{I}{10^{14}} \right)^{3/4} \lambda^{-1/4} \left( \frac{A}{Z} \right)^{7/16} \left( \frac{Z \times t}{3.5} \right)^{-1/8},
\]

where \(I\) is the irradiance on target with the unit of W/cm\(^2\); \(\lambda\) is the laser wavelength in μm; \(A\) and \(Z\) are, respectively, the mass number and the atomic number of the target; \(t\) is the time in ns. Figure 3 shows the effective pressure in the irradiated region with the laser peak power density of 0 \(\sim 3.0 \times 10^{12}\) W/cm\(^2\). In this study, the maximum pressure induced by the laser reached approximately 1.5 Mbar. According to the studies of Greene et al. in II–VI compounds \([28]\), the solid-solid transition point, that is, the zinc blende-wurtzite phase transition, of ZnSe is approximately 0.55 Mbar. In our experiments, the ablation pressure induced by the femtosecond laser pulses on the ZnSe single crystals was in the range of 1.0 Mbar to 1.5 Mbar as shown in the shadow area of Figure 3. This exceeds the solid-solid transition pressure 0.55 Mbar (the dashed line in Figure 3). Therefore, the wurtzite-phase ZnSe nanoparticles transferred from the zinc blende phase may be caused by high ablation pressure resulting from the femtosecond laser pulses, and the accompanied increase in surface to volume ratio in the nanoparticles.
In summary, we demonstrated a simple and reliable approach to obtain the thermally metastable and pure ZnSe nanoparticles. The spherical-shape wurtzite ZnSe nanoparticles with the average diameter of <25 nm can be well produced through the femtosecond laser ablation technique. While the femtosecond laser pulses are focused on the surface of a ZnSe wafer in air, the ablated plume cannot expand as rapidly as those in vacuum chamber and then causes an instantaneous high-energy and high-pressure region around the laser focused point; meanwhile, a large amount of ZnSe nanoparticles was fabricated on the surface of a ZnSe wafer. During the formation of ZnSe nanoparticles, the structural phase further changes from the zinc blende phase to the metastable wurtzite phase due to the ultrahigh localized ablation pressure caused by the rapid injection of high laser energy within a femtosecond time scale.

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References

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